## Low Voltage Precision Adjustable Shunt Regulator

The TLV431A series are precision low voltage shunt regulators that are programmable over a wide voltage range of 1.24 V to 16 V. These series feature a guaranteed reference accuracy of  $\pm 1.0\%$  at 25°C and  $\pm 2.0\%$  over the entire industrial temperature range of -40°C to 85°C. These devices exhibit a sharp low current turn—on characteristic with a low dynamic impedance of 0.20  $\Omega$  over an operating current range of 100  $\mu A$  to 20 mA. This combination of features makes this series an excellent replacement for zener diodes in numerous applications circuits that require a precise reference voltage. When combined with an optocoupler, the TLV431A can be used as an error amplifier for controlling the feedback loop in isolated low output voltage (3.0 V to 3.3 V) switching power supplies. These devices are available in economical TSOP–5 and TO–92 packages.

#### **Features**

- Programmable Output Voltage Range of 1.24 V to 16 V
- Voltage Reference Tolerance ± 1.0%
- Sharp Low Current Turn-On Characteristic
- Low Dynamic Output Impedance of  $0.20 \Omega$  from  $100 \mu A$  to 20 mA
- Wide Operating Current Range of 50 μA to 20 mA
- Micro Miniature TSOP-5 and TO-92 Packages

#### **Applications**

- Low Output Voltage (3.0 V to 3.3 V) Switching Power Supply Error Amplifier
- Adjustable Voltage or Current Linear and Switching Power Supplies
- Voltage Monitoring
- Current Source and Sink Circuits
- Analog and Digital Circuits Requiring Precision References
- Low Voltage Zener Diode Replacements

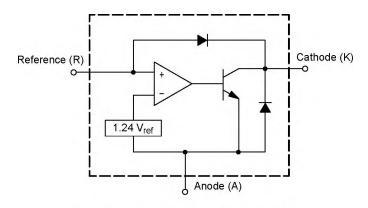


Figure 1. Representative Block Diagram



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#### MARKING DIAGRAM



TO-92 LP SUFFIX CASE 29



- Reference
   Anode
- 3. Cathode

A = Assembly Location

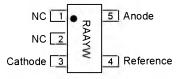
= Wafer Lot = Year

WW = Work Week



TSOP-5 SN SUFFIX CASE 483

# PIN CONNECTIONS AND DEVICE MARKING



(Top View)

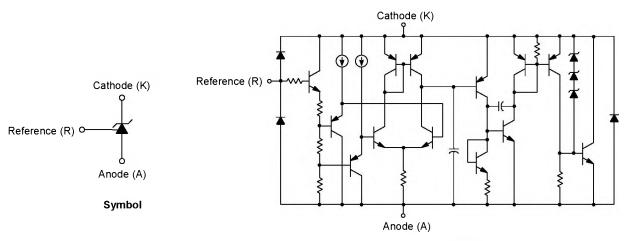
RAA = Device Code

Y = Year

W = Work Week

#### ORDERING INFORMATION

Device	Package	Shipping
TLV431ALP	TO-92	6000 / Box
TLV431ALPRA	TO-92	2000 / Tape & Reel
TLV431ALPRE	TO-92	2000 / Tape & Reel
TLV431ALPRM	TO-92	2000 / Ammo Pack
TLV431ALPRP	TO-92	2000 / Ammo Pack
TLV431ASNT1	TSOP-5	3000 / Tape & Reel



The device contains 13 active transistors.

Figure 2. Representaive Schematic Diagram

## MAXIMUM RATINGS (Full operating ambient temperature range applies, unless otherwise noted)

Rating	Symbol	Value	Unit	
Cathode to Anode Voltage	V <sub>KA</sub>	18	V	
Cathode Current Range, Continuous (Note 1)	IK	-20 to 25	mA	
Reference Input Current Range, Continuous	I <sub>ref</sub>	- 0.05 to 10	mA	
Thermal Characteristics LP Suffix Package Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case SN Suffix Package Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> R <sub>θJC</sub> R <sub>θJA</sub>	178 83 226	°C/W	
Operating Junction Temperature	TJ	150	°C	
Operating Ambient Temperature Range (Note 1)	T <sub>A</sub>	- 40 to 85	°C	
Storage Temperature Range	T <sub>stg</sub>	- 65 to 150	°C	

<sup>1.</sup> Maximum package power dissipation limits must not be exceeded.

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL-STD-883, Method 3015.

Machine Model Method 200 V.

#### RECOMMENDED OPERATING CONDITIONS

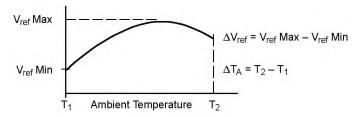
Condition	Symbol	Min	Max	Unit
Cathode to Anode Voltage	V <sub>KA</sub>	$V_{ref}$	16	V
Cathode Current	lκ	0.1	20	mA

#### **TLV431A**

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reference Voltage (Figure 1) $(V_{KA} = V_{ref}, I_K = 10 \text{ mA}, T_A = 25^{\circ}\text{C})$ $(T_A = T_{low} \text{ to } T_{high}, \text{ Note 2})$	V <sub>ref</sub>	1.228 1.215	1.240 —	1.252 1.265	V
Reference Input Voltage Deviation Over Temperature (Figure 1) $(V_{KA} = V_{ref}, I_K = 10 \text{ mA}, T_A = T_{low} \text{ to } T_{high}, \text{ Notes 2, 3)}$	$\Delta V_{ref}$	-	7.2	20	mV
Ratio of Reference Input Voltage Change to Cathode Voltage Change (Figure 2) ( $V_{KA}$ = $V_{ref}$ to 16 V, $I_{K}$ = 10 mA)	$\frac{\Delta V_{ref}}{\Delta V_{KA}}$	-	- 0.6	-1.5	mV V
Reference Terminal Current (Figure 2) (I <sub>K</sub> = 10 mA, R1 = 10 k $\Omega$ , R2 = open)	I <sub>ref</sub>	-	0.15	0.3	μΑ
Reference Input Current Deviation Over Temperature (Figure 2) (I <sub>K</sub> = 10 mA, R1 = 10 k $\Omega$ , R2 = Open, Notes 2, 3)	$\Delta$ I $_{ m ref}$		0.04	0.08	μΑ
Minimum Cathode Current for Regulation (Figure 1)	I <sub>K(min)</sub>	-	55	80	μΑ
Off–State Cathode Current (Figure 3) $(V_{KA} = 6.0 \text{ V}, V_{ref} = 0)$ $(V_{KA} = 16 \text{ V}, V_{ref} = 0)$	I <sub>K(off)</sub>	-	0.01 0.012	0.04 0.05	μΑ
Dynamic Impedance (Figure 1) $(V_{KA} = V_{ref}, I_K = 0.1 \text{ mA to } 20 \text{ mA}, f \le 1.0 \text{ kHz}, \text{ Note 4})$	Z <sub>KA</sub>	1.4	0.25	0.4	Ω

- 2. Ambient temperature range: T<sub>low</sub> = -40°C, T<sub>high</sub> = 85°C.
- 3. The deviation parameters  $\Delta V_{ref}$  and  $\Delta I_{ref}$  are defined as the difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.



The average temperature coefficient of the reference input voltage,  $\alpha V_{ref}$  is defined as:

$$\alpha V_{\mbox{ref}} \left( \frac{\mbox{ppm}}{^{\circ}\mbox{C}} \right) = \frac{\left( \frac{(\Delta V_{\mbox{ref}})}{V_{\mbox{ref}} \left( \mbox{T}_{\mbox{A}} = 25^{\circ}\mbox{C} \right)} \times 10^{6} \right)}{\Delta T_{\mbox{A}}} \label{eq:eq:av_ref}$$

 $\alpha V_{ref}$  can be positive or negative depending on whether  $V_{ref}$  Min or  $V_{ref}$  Max occurs at the lower ambient temperature, refer to Figure 6. Example:  $\Delta V_{ref} = 7.2$  mV and the slope is positive,

$$V_{ref}$$
 @ 25°C = 1.241 V  $\Delta T_A$  = 125°C

$$\alpha V_{ref} \left( \frac{ppm}{^{\circ}C} \right) = \frac{\frac{0.0072}{1.241} \times 10^{6}}{125} = 46 \text{ ppm/}^{\circ}C$$

4. The dynamic impedance  $Z_{KA}$  is defined as:

$$|z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$$

When the device is operating with two external resistors, R1 and R2, (refer to Figure 2) the total dynamic impedance of the circuit is given by:

$$|Z_{KA}'| = |Z_{KA}| \times \left(1 + \frac{R1}{R2}\right)$$

## **TLV431A**

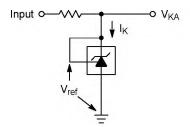


Figure 3. Test Circuit for V<sub>KA</sub> = V<sub>ref</sub>

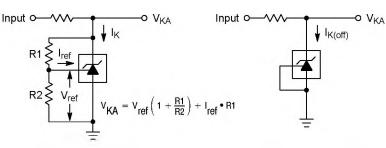


Figure 4. Test Circuit for  $V_{KA} > V_{ref}$ 

Figure 5. Test Circuit for I<sub>K(off)</sub>

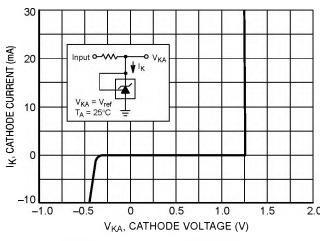


Figure 6. Cathode Current vs. Cathode Voltage

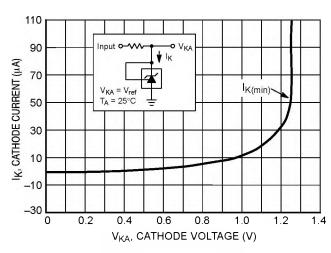


Figure 7. Cathode Current vs. Cathode Voltage

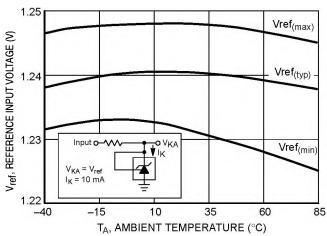


Figure 8. Reference Input Voltage versus
Ambient Temperature

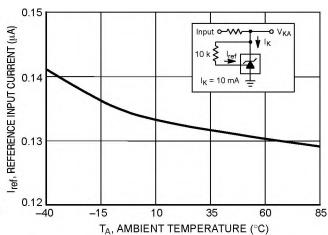
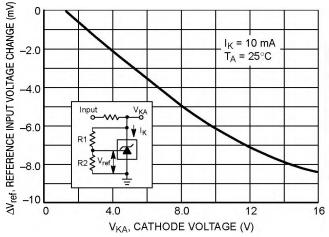


Figure 9. Reference Input Current versus Ambient Temperature

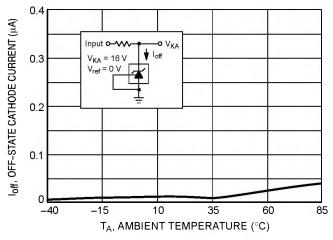


4.0

| Input | V<sub>KA</sub> = 16 V | V<sub>ref</sub> = 0 V | V<sub>KA</sub> | V<sub>KA</sub> = 16 V | V<sub>ref</sub> = 0 V | V<sub>KA</sub> = 25°C | V<sub>KA</sub> | CATHODE VOLTAGE (V)

Figure 10. Reference Input Voltage Change versus Cathode Voltage

Figure 11. Off-State Cathode Current versus Cathode Voltage



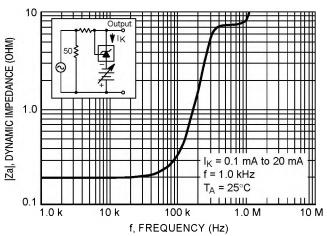
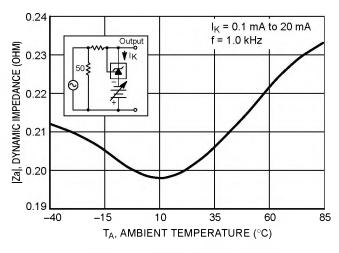


Figure 12. Off-State Cathode Current versus
Ambient Temperature

Figure 13. Dynamic Impedance versus Frequency



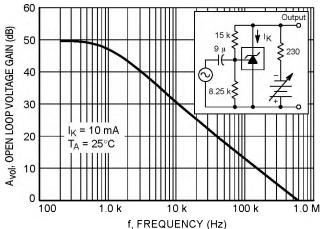


Figure 14. Dynamic Impedance versus Ambient Temperature

Figure 15. Open–Loop Voltage Gain versus Frequency

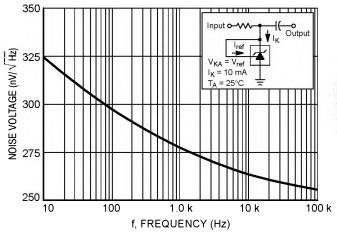


Figure 16. Spectral Noise Density

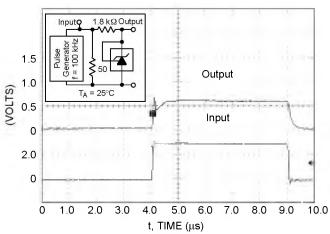


Figure 17. Pulse Response

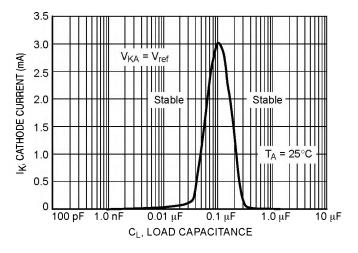


Figure 18. Stability Boundary Conditions

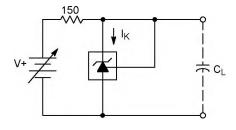


Figure 19. Test Circuit for Figure 16

## **TYPICAL APPLICATIONS**

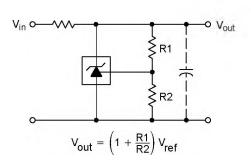
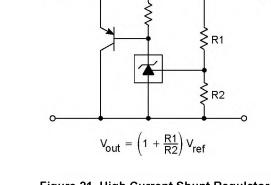


Figure 20. Shunt Regulator



O V<sub>out</sub>

Figure 21. High Current Shunt Regulator

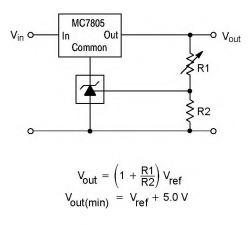


Figure 22. Output Control for a Three Terminal Fixed Regulator

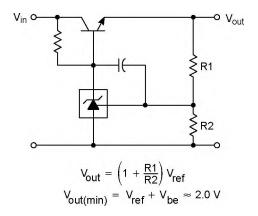


Figure 23. Series Pass Regulator

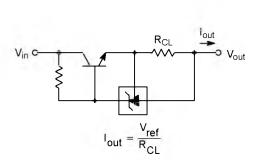


Figure 24. Constant Current Source

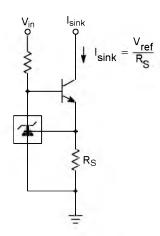


Figure 25. Constant Current Sink

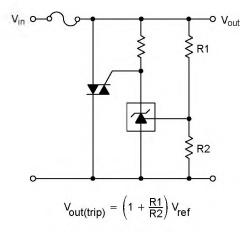


Figure 26. TRIAC Crowbar

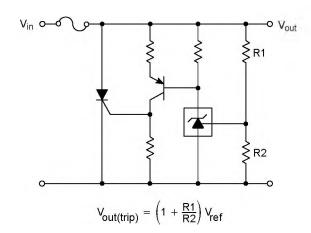
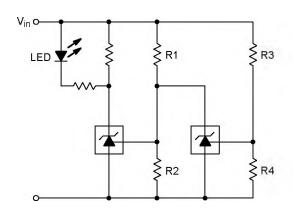


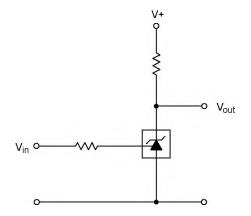
Figure 27. SCR Crowbar



L.E.D. indicator is 'ON' when  $V_{in}$  is between the upper and lower limits,

Lower limit = 
$$\left(1 + \frac{R1}{R2}\right) V_{ref}$$
  
Upper limit =  $\left(1 + \frac{R3}{R4}\right) V_{ref}$ 

Figure 28. Voltage Monitor



V <sub>in</sub>	V <sub>out</sub>	
< V <sub>ref</sub>	V+	
> V <sub>ref</sub>	≈ 0.74 V	

Figure 29. Single–Supply Comparator with Temperature–Compensated Threshold

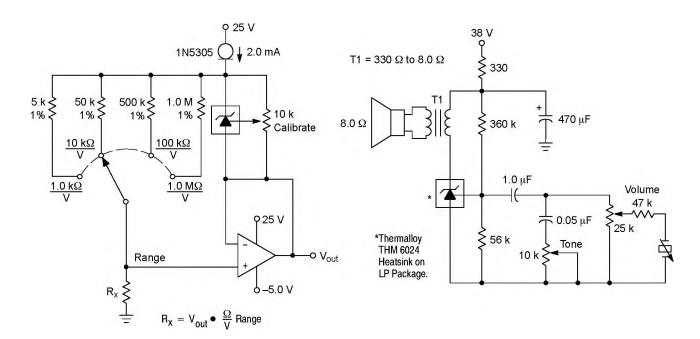


Figure 30. Linear Ohmmeter

Figure 31. Simple 400 mW Phono Amplifier

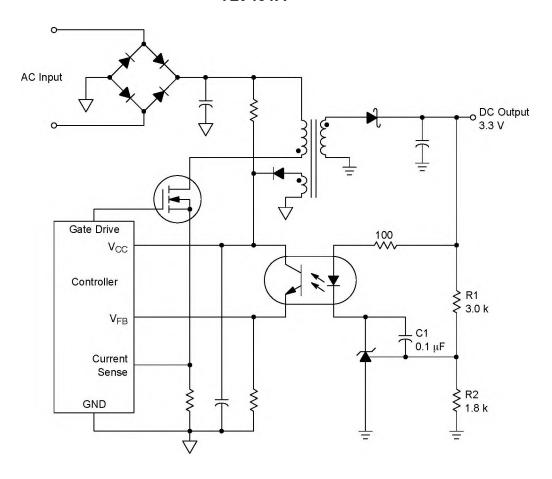


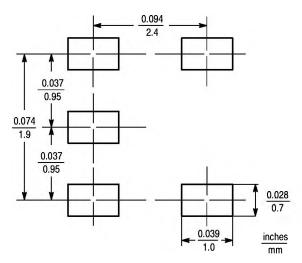
Figure 32. Isolated Output Line Powered Switching Power Supply

The above circuit shows the TLV431A as a compensated amplifier controlling the feedback loop of an isolated output line powered switching regulator. The output voltage is programmed to 3.3 V by the resistors values selected for R1 and R2. The minimum output voltage that can be programmed with this circuit is 2.64 V, and is limited by the sum of the reference voltage (1.24 V) and the forward drop of the optocoupler light emitting diode (1.4 V). Capacitor C1 provides loop compensation.

## MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



TSOP-5 (Footprint Compatible with SOT-23-5)